Linear Voltage Regulator, LDO, High PSRR, 500 mA

The NCP4687 is a CMOS 500 mA LDO linear voltage regulator with high output voltage accuracy which features a high ripple rejection, low supply current with low dropout and chip enable with built—in low $R_{\rm DS(on)}$ NMOS transistor for fast output capacitor discharging as option. The device is composed of the voltage reference unit, error amplifier, resistor divider for output voltage sensing or precise output voltage setting. The current limit and thermal shutdown makes the device very suitable for industrial applications and portable communication equipments.

Features

- Operating Input Voltage Range: 2.5 V to 5.25 V
- Output Voltage Range: 0.7 to 3.6 V (available in 0.1 V steps)
- $\pm 0.8\%$ Output Voltage Accuracy @ $V_{out} > 1.8 \text{ V}$
- Output noise : $40 \mu V_{rms}$
- Line Regulation: 0.02%/V
- Current Limit Circuit
- High PSRR: 75 dB at 1 kHz, 70 dB at 10 kHz
- Thermal Shutdown
- Available in SOT-23-5, SOT-89-5 and uDFN 1.2 x 1.2 mm Packages
- These Devices are Pb-Free and are RoHS Compliant

Typical Applications

- Home Appliances, Industrial Equipment
- DVB-T and DVB-S Receivers
- Car Audio Equipment, Navigation Systems
- Notebook Adaptors, LCD TVs, Cordless Phones and Private LAN Systems

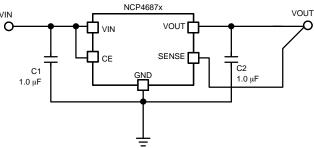
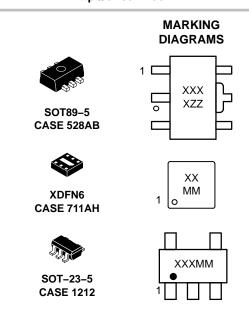


Figure 1. Typical Application Schematic



ON Semiconductor™

http://onsemi.com



XX, XXX= Specific Device Code

ZZ = Lot Code MM = Date Code

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 15 of this data sheet.

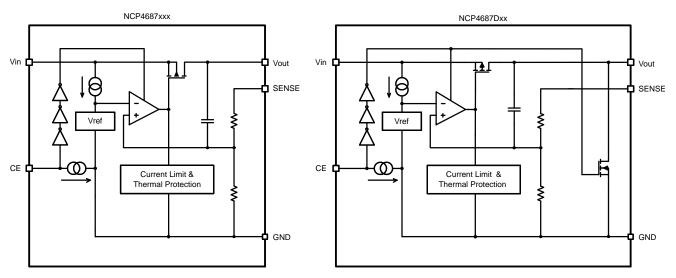


Figure 2. Simplified Schematic Block Diagram

PIN FUNCTION DESCRIPTION

Pin No. SOT-23-5	Pin No. SOT-89-5	Pin No. DFN1212	Pin Name	Description
1	4	6	VIN	Input pin
2	2	3	GND	Ground pin
3	3	4	CE	Chip enable pin ("H" active)
4	1	2	SENSE	Output Voltage Sensing
5	5	1	VOUT	Output pin
		5	NC	Non Connected
		*EP	EP	Exposed Pad (leave floating or connect to GND)

ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage	V_{IN}	0 – 6	V
Output Voltage	Vouт	-0.3 to VIN - 0.3	V
Chip Enable Input	VCE	-0.3 - 6	V
Power Dissipation SOT-23-5	P_{D}	420	mW
Power Dissipation uDFN 1.2 x 1.2 mm		600	
Power Dissipation SOT-89-5		900	
Junction Temperature	T_J	-40 to 150	°C
Storage Temperature	T _{STG}	-55 to 125	°C
ESD Capability, Human Body Model (Note 1)	ESD _{HBM}	2000	V
ESD Capability, Machine Model (Note 1)	ESD _{MM}	200	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. This device series incorporates ESD protection and is tested by the following methods:
ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114)
ESD Machine Model tested per AEC-Q100-003 (EIA/JESD22-A115)
Latchup Current Maximum Rating tested per JEDEC standard: JESD78

THERMAL CHARACTERISTICS

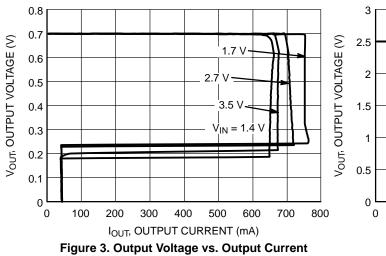
Rating	Symbol	Value	Unit
Thermal Characteristics, SOT–23–5 Thermal Resistance, Junction–to–Air	$R_{\theta JA}$	238	°C/W
Thermal Characteristics, uDFN 1.2x1.2 Thermal Resistance, Junction-to-Air	$R_{ hetaJA}$	167	°C/W
Thermal Characteristics, SOT–89–5 Thermal Resistance, Junction–to–Air	$R_{ heta JA}$	111	°C/W

ELECTRICAL CHARACTERISTICS $-40^{\circ}C \le T_A \le 85^{\circ}C$; $C_{IN} = C_{OUT} = 1.0~\mu\text{F}$, unless otherwise noted. Typical values are at $T_A = +25^{\circ}C$.

$\begin{tabular}{ l l l l l l l l l l l l l l l l l l l$	V DUT	2.5 /OUT + 1 x0.992 x0.985 -18 -55	±30 ±100 1 0.02	5.25 5.25 x1.008 x1.015 +18 +55	V V V mV mV ppm/°C
Output Voltage $Ta = 25^{\circ}C$, $VouT > 1.8 \text{ V}$ $-40^{\circ}C < Ta < 85^{\circ}C$, $VouT > 1.8 \text{ V}$ $Ta = 25^{\circ}C$, $VouT \le 1.8 \text{ V}$ $-40^{\circ}C < Ta < 85^{\circ}C$, $VouT \le 1.8 \text{ V}$ Output Voltage Temp. $-40^{\circ}C < Ta < 85^{\circ}C$, $VouT > 1.8 \text{ V}$ Coefficient $-40^{\circ}C < Ta < 85^{\circ}C$, $VouT \le 1.8 \text{ V}$ Load Regulation $1 \text{ mA} < \text{louT} \le 500 \text{ mA}$ Load Line Regulation Set $VouT + 0.5 \text{ V} < ViN < 5.25 \text{ V}$ Line Included	DUT	x0.992 x0.985 -18	±100	x1.008 x1.015 +18 +55	V mV mV ppm/°C
$-40^{\circ}\text{C} < \text{Ta} < 85^{\circ}\text{C}, \text{ Vout} > 1.8 \text{ V}$ $\text{Ta} = 25^{\circ}\text{C}, \text{ Vout} \le 1.8 \text{ V}$ $-40^{\circ}\text{C} < \text{Ta} < 85^{\circ}\text{C}, \text{ Vout} \le 1.8 \text{ V}$ $-40^{\circ}\text{C} < \text{Ta} < 85^{\circ}\text{C}, \text{ Vout} \le 1.8 \text{ V}$ $\text{Output Voltage Temp.}$ Coefficient $-40^{\circ}\text{C} < \text{Ta} < 85^{\circ}\text{C}, \text{ Vout} > 1.8 \text{ V}$ $-40^{\circ}\text{C} < \text{Ta} < 85^{\circ}\text{C}, \text{ Vout} \le 1.8 \text{ V}$ Load Regulation $1 \text{ mA} < \text{lout} \le 500 \text{ mA}$ $\text{Load Line Regulation}$ $\text{Set Vout} + 0.5 \text{ V} < \text{Vin} < 5.25 \text{ V}$ $\text{Line Dropout Voltage}$ $\text{I}_{\text{OUT}} = 500 \text{ mA}$ $0.7 \text{ V} \le \text{V}_{\text{OUT}} < 0.8 \text{ V}$ $0.8 \text{ V} \le \text{V}_{\text{OUT}} < 0.9 \text{ V}$	d _{Reg}	x0.985 –18	±100	x1.015 +18 +55	V mV mV ppm/°C
	d _{Reg}	-18	±100	+18 +55	mV mV ppm/°C
$-40^{\circ}\text{C} < \text{Ta} < 85^{\circ}\text{C}, \text{ Vout} \le 1.8 \text{ V}$ Output Voltage Temp. $-40^{\circ}\text{C} < \text{Ta} < 85^{\circ}\text{C}, \text{ Vout} > 1.8 \text{ V}$ $-40^{\circ}\text{C} < \text{Ta} < 85^{\circ}\text{C}, \text{ Vout} \le 1.8 \text{ V}$ $-40^{\circ}\text{C} < \text{Ta} < 85^{\circ}\text{C}, \text{ Vout} \le 1.8 \text{ V}$ Load Regulation $1 \text{ mA} < \text{lout} \le 500 \text{ mA}$ Load Line Regulation Set Vout + 0.5 V < Vin < 5.25 V Line Dropout Voltage $1_{\text{OUT}} = 500 \text{ mA}$ $0.7 \text{ V} \le \text{V}_{\text{OUT}} < 0.8 \text{ V}$ $0.8 \text{ V} \le \text{V}_{\text{OUT}} < 0.9 \text{ V}$	Reg		±100	+55	mV ppm/°C mV
	Reg	-55	±100	20	ppm/°C
	Reg		±100		mV
$-40^{\circ}\text{C} < \text{Ta} < 85^{\circ}\text{C}, \text{Vout} \le 1.8 \text{ V}$ Load Regulation $1 \text{ mA} < \text{Iout} \le 500 \text{ mA} \qquad \text{Load}$ Line Regulation $\text{Set Vout} + 0.5 \text{ V} < \text{Vin} < 5.25 \text{ V} \qquad \text{Line}$ Dropout Voltage $I_{\text{OUT}} = 500 \text{ mA} \qquad 0.7 \text{ V} \le \text{V}_{\text{OUT}} < 0.8 \text{ V} \qquad \text{VD}$ $0.8 \text{ V} \le \text{V}_{\text{OUT}} < 0.9 \text{ V}$	Reg		1		
Line Regulation Set VouT + 0.5 V < VIN < 5.25 V Line Dropout Voltage $I_{OUT} = 500 \text{ mA}$ $0.7 \text{ V} \leq V_{OUT} < 0.8 \text{ V}$ VD $0.8 \text{ V} \leq V_{OUT} < 0.9 \text{ V}$	Reg				
Line Regulation Set VouT + 0.5 V < VIN < 5.25 V Line Dropout Voltage $I_{OUT} = 500 \text{ mA}$ $0.7 \text{ V} \leq V_{OUT} < 0.8 \text{ V}$ VD $0.8 \text{ V} \leq V_{OUT} < 0.9 \text{ V}$	Reg		0.02	0.1	0/ /\
Dropout Voltage $I_{OUT} = 500 \text{ mA} \qquad 0.7 \text{ V} \le V_{OUT} < 0.8 \text{ V} \qquad \text{VD}$ $0.8 \text{ V} \le V_{OUT} < 0.9 \text{ V}$					%/V
			0.58	0.88	V
$0.9 \text{ V} \leq \text{V}_{OUT} < 1.0 \text{ V}$			0.52	0.80	
		ŀ	0.45	0.70	
$1.0 \text{ V} \le \text{V}_{\text{OUT}} < 1.2 \text{ V}$			0.42	0.64	
$1.2 \text{ V} \le \text{V}_{\text{OUT}} < 1.4 \text{ V}$			0.35	0.53	
$1.4 \text{ V} \le \text{V}_{\text{OUT}} < 1.8 \text{ V}$			0.31	0.48	
$1.8 \text{ V} \le \text{V}_{\text{OUT}} < 2.1 \text{ V}$			0.27	0.41	
$2.1 \text{ V} \le \text{V}_{\text{OUT}} < 2.5 \text{ V}$			0.25	0.38	
$2.5 \text{ V} \le \text{V}_{\text{OUT}} < 3.0 \text{ V}$			0.23	0.34	
$3.0 \text{ V} \le \text{V}_{\text{OUT}} < 3.6 \text{ V}$			0.22	0.32	
Output Current Iou	UT	500			mA
Short Current Limit V _{OUT} = 0 V	SC SC		50		mA
Quiescent Current I _{OUT} = 0 mA VouT > 1.5 V Ic	Q		80	115	μΑ
Vout ≤ 1.5 V			75		
Standby Current V _{IN} = V _{IN max} , V _{CE} = 0 V IST	ТВ		0.1	1.0	μΑ
CE Pin Pull–Down Current IPI	D		0.3	0.6	μΑ
CE Pin Threshold Voltage CE Input Voltage "H" Vot	EH	1.0		V _{IN}	V
CE Input Voltage "L" Vol	EL			0.4	
Power Supply Rejection $V_{OUT} \le 2.0 \text{ V } @ \text{ VIN} = 3.0 \text{ V}, \\ V_{OUT} > 2.0 \text{ V } @ \text{ VIN} = $	RR		75		dB
$= \text{Set V}_{\text{OUT}} + 1.0 \text{ V}, \\ \Delta V_{\text{IN}}_{\text{PK}-\text{PK}} = 0.2 \text{ V}, \\ I_{\text{OUT}} = 30 \text{ mA} $ f = 10 kHz		-	70		
Output Noise Voltage $I_{OUT} = 30 \text{ mA}$, f = 10 Hz to 100 kHz, $V_{OUT} > 1.8 \text{ V}$ VNO	DISE		20 х Vouт		μV _{rms}
I_{OUT} = 30 mA, f = 10 Hz to 100 kHz, $V_{OUT} \le 1.8 \text{ V}$			40 х Vouт		
Thermal Shutdown / Hysteresis			165/65		°C
Auto-discharge N-MOS VIN = 4.0 V, VCE = 0.0 V (Note 2) Resistance	S(on)		60		Ω

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

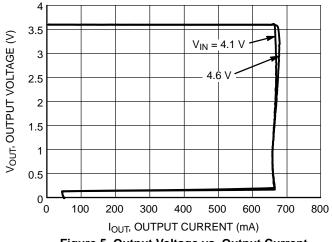
2.



 $V_{IN} = 4.0 V$ 3.5 V 3.0 √ 300 100 200 400 500 600 700 800 900 IOUT, OUTPUT CURRENT (mA)

0.7 V Version

Figure 4. Output Voltage vs. Output Current 2.5 V Version



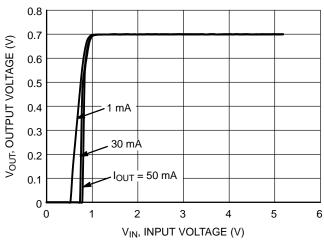
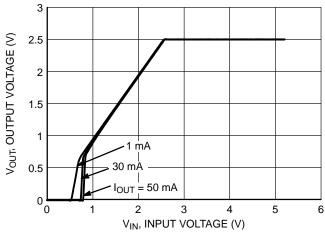


Figure 5. Output Voltage vs. Output Current 3.6 V Version

Figure 6. Output Voltage vs. Input Voltage 0.7 V Version



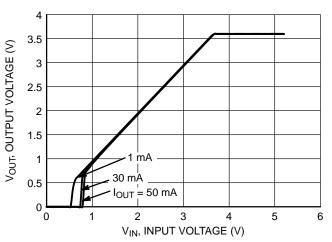
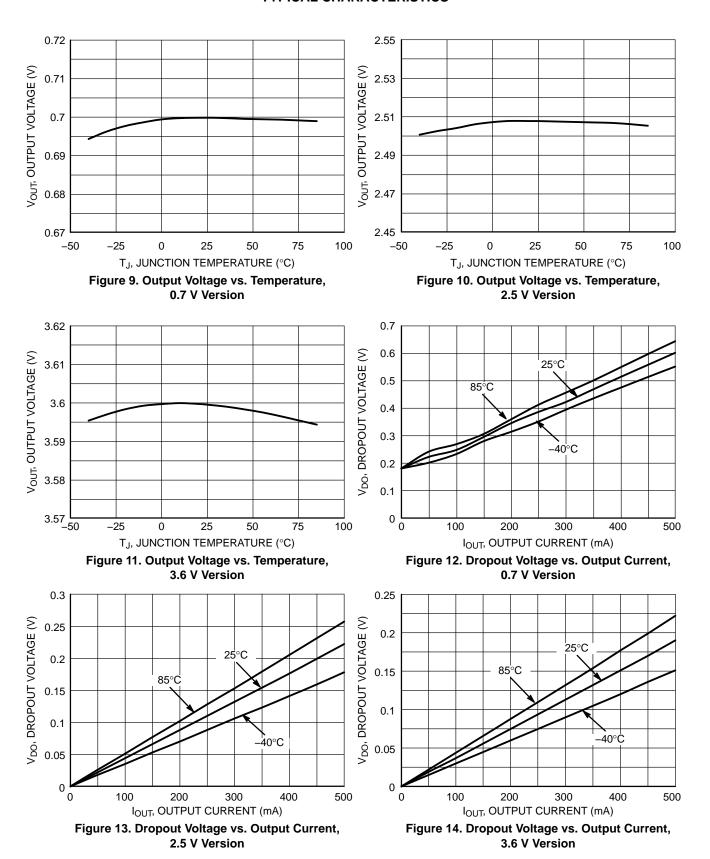
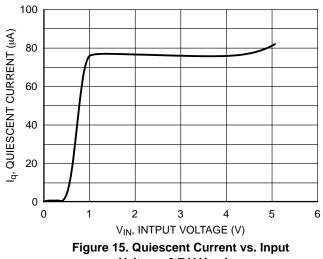


Figure 7. Output Voltage vs. Input Voltage 2.5 V Version

Figure 8. Output Voltage vs. Input Voltage 3.6 V Version





Voltage, 0.7 V Version

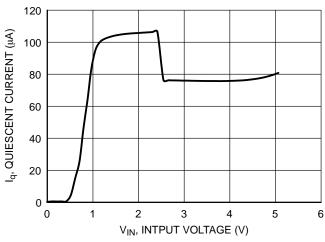


Figure 16. Quiescent Current vs. Input Voltage, 2.5 V Version

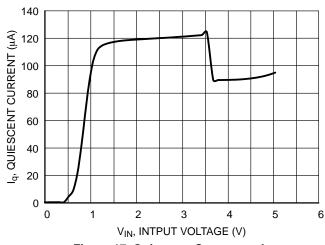


Figure 17. Quiescent Current vs. Input Voltage, 3.6 V Version

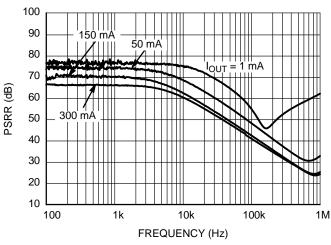


Figure 18. PSRR vs. Frequency, 0.7 V Version

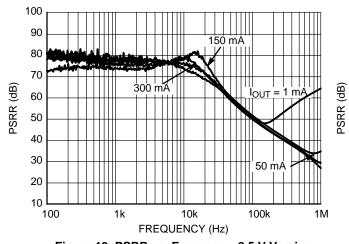


Figure 19. PSRR vs. Frequency, 2.5 V Version

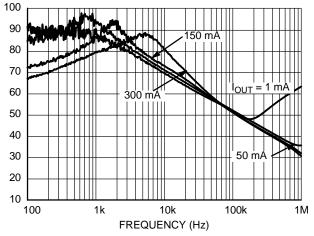


Figure 20. PSRR vs. Frequency, 3.6 V Version

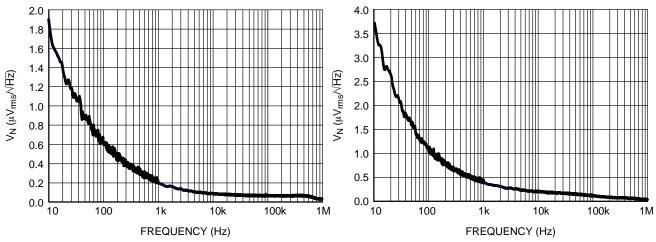


Figure 21. Output Noise vs. Frequency, 0.7 V Version

Figure 22. Output Noise vs. Frequency, 2.5 V Version

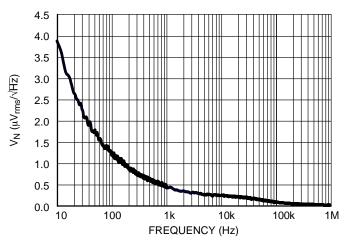


Figure 23. Output Noise vs. Frequency, 3.6 V Version

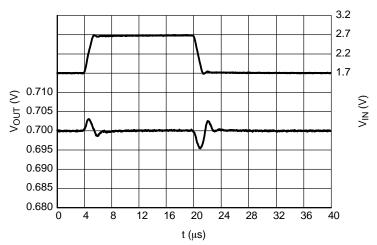


Figure 24. Line Transients, 0.7 V Version

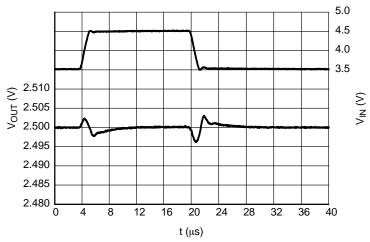


Figure 25. Line Transients, 2.5 V Version

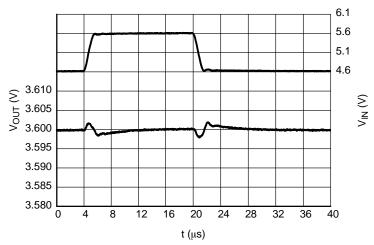


Figure 26. Line Transients, 3.6 V Version

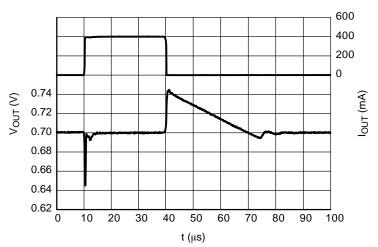


Figure 27. Load Transients, 0.7 V Version, Load Step 1 mA to 400 mA

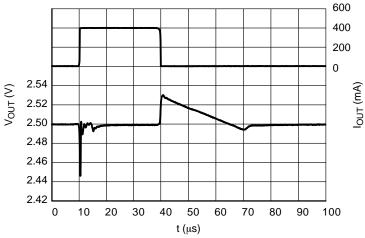


Figure 28. Load Transients, 2.5 V Version, Load Step 1 mA to 400 mA

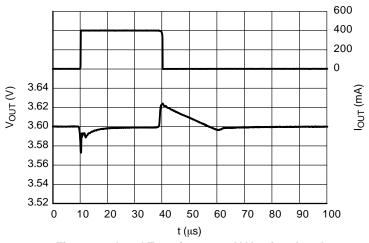


Figure 29. Load Transients, 3.6 V Version, Load Step 1 mA to 400 mA

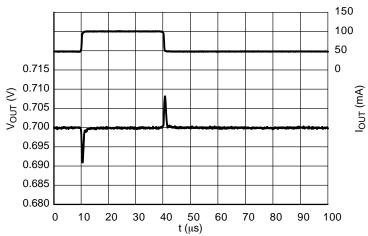


Figure 30. Load Transients, 0.7 V Version, Load Step 50 mA to 100 mA

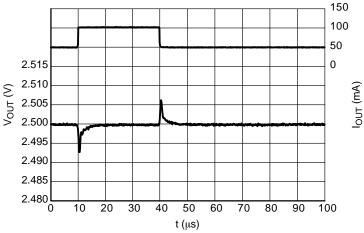


Figure 31. Load Transients, 2.5 V Version, Load Step 50 mA to 100 mA

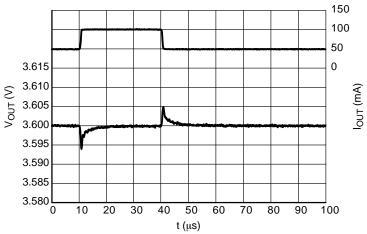


Figure 32. Load Transients, 3.6 V Version, Load Step 50 mA to 100 mA

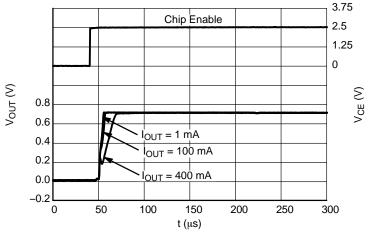


Figure 33. Turn On with CE Behavior, 0.7 V Version

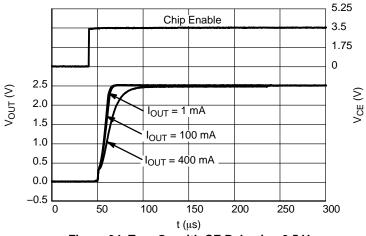


Figure 34. Turn On with CE Behavior, 2.5 V Version

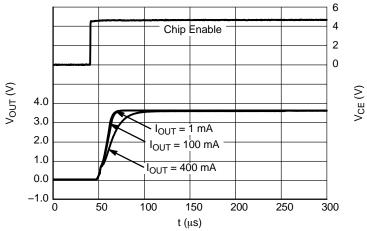


Figure 35. Turn On with CE Behavior, 3.6 V Version

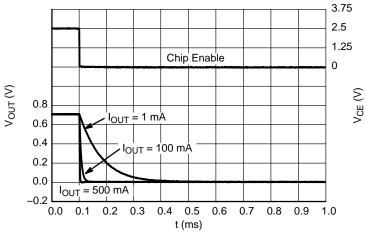


Figure 36. Turn Off with CE Behavior, 0.7 V Version

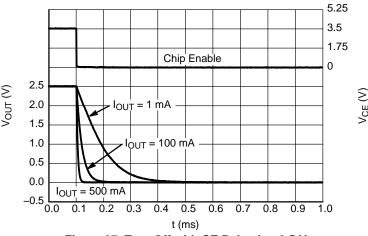


Figure 37. Turn Off with CE Behavior, 2.5 V Version

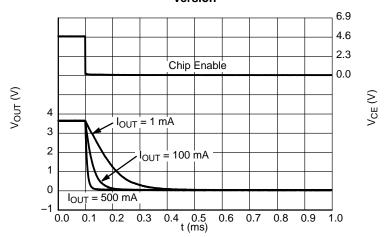


Figure 38. Turn Off with CE Behavior, 3.6 V Version

APPLICATION INFORMATION

A typical application circuit for NCP4687 series is shown in the Figure 39.

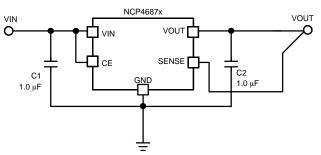


Figure 39. Typical Application Schematic

Input Decoupling Capacitor (C1)

A $1.0~\mu F$ ceramic input decoupling capacitor should be connected as close as possible to the input and ground pin of the NCP4687 device. Higher values and lower ESR improves line transient response.

Output Decoupling Capacitor (C2)

A 1.0 μF ceramic output decoupling capacitor is sufficient to achieve stable operation of the device. If tantalum capacitor is used, and its ESR is high, the loop oscillation may result. The capacitor should be connected as close as possible to the output and ground pin. Larger values and lower ESR improves dynamic parameters.

Enable Operation

The enable pin CE may be used for turning the regulator on and off. The IC is switched on when a high level voltage is applied to the CE pin. The enable pin has an internal pull down current source which assure off state of LDO in case the CE pin will stay floating. If the enable function is not needed connect CE pin to VIN.

The D version of the NCP4687 device includes a transistor between Vout and GND that is used for faster discharging of the output capacitor. This function is activated when the IC goes into disable mode.

Thermal Consideration

As a power across the IC increase, it might become necessary to provide some thermal relief. The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material, and also the ambient temperature affect the rate of temperature increase for the part. When the device has good thermal conductivity through the PCB the junction temperature will be relatively low in high power dissipation applications.

The IC includes internal thermal shutdown circuit that stops operation of regulator, if junction temperature is higher than 165°C. After that, when junction temperature decreases below 100°C, the operation of voltage regulator would restart. While high power dissipation condition is, the regulator starts and stops repeatedly and protects itself against overheating.

Sense Pin

The SENSE pin improves significantly the load regulation. The connection resistance between the LDO and the load given by PCB parameters has reduced impact to load regulation. If possible, use wide PCB traces as short as possible.

ORDERING INFORMATION

Device	Marking	Nominal Output Voltage	Feature	Package	Shipping [†]
NCP4687DH12T1G	A12D	1.2 V	Auto discharge	SOT-89 (Pb-Free)	1000 / Tape & Reel
NCP4687DH15T1G	A15D	1.5 V	Auto discharge	SOT-89 (Pb-Free)	1000 / Tape & Reel
NCP4687DH18T1G	A18D	1.8 V	Auto discharge	SOT-89 (Pb-Free)	1000 / Tape & Reel
NCP4687DH25T1G	A25D	2.5 V	Auto discharge	SOT-89 (Pb-Free)	1000 / Tape & Reel
NCP4687DH33T1G	A33D	3.3 V	Auto discharge	SOT-89 (Pb-Free)	1000 / Tape & Reel
NCP4687DMX18TCG	9P	1.8 V	Auto discharge	XDFN6 (Pb-Free)	5000 / Tape & Reel
NCP4687DMX25TCG	9X	2.5 V	Auto discharge	XDFN6 (Pb-Free)	5000 / Tape & Reel
NCP4687DMX33TCG	0G	3.3 V	Auto discharge	XDFN6 (Pb-Free)	5000 / Tape & Reel
NCP4687DSN18T1G	J18	1.8 V	Auto discharge	SOT-23 (Pb-Free)	3000 / Tape & Reel
NCP4687DSN25T1G	J25	2.5 V	Auto discharge	SOT-23 (Pb-Free)	3000 / Tape & Reel
NCP4687DSN28T1G	J28	2.8 V	Auto discharge	SOT-23 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MECHANICAL CASE OUTLINE

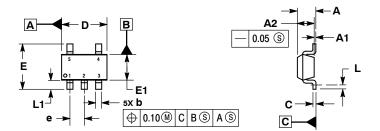
PACKAGE DIMENSIONS



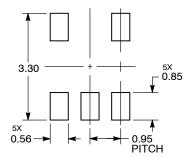


SOT-23 5-LEAD CASE 1212-01 **ISSUE A**

DATE 28 JAN 2011



RECOMMENDED **SOLDERING FOOTPRINT***



DIMENSIONS: MILLIMETERS

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
 ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSIONS: MILLIMETERS.
 3. DATUM C IS THE SEATING PLANE.

	MILLIMETERS		
DIM	MIN	MAX	
Α		1.45	
A1	0.00	0.10	
A2	1.00	1.30	
b	0.30	0.50	
С	0.10	0.25	
D	2.70	3.10	
E	2.50	3.10	
E1	1.50 1.80		
е	0.95 BSC		
L	0.20		
L1	0.45	0.75	

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

DOCUMENT NUMBER:	98ASH70518A	Electronic versions are uncontrolled except when accessed directly from the Document Repos Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SOT-23 5-LEAD		PAGE 1 OF 1

ON Semiconductor and (III) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



SOT-89, 5 LEAD CASE 528AB-01 **ISSUE O**

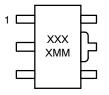
DATE 23 NOV 2009

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

- Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 LEAD THICKNESS INCLUDES LEAD FINISH.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD
 FLASH, PROTRUSIONS, OR GATE BURRS.
 DIMENSIONS L, L2, L3, L4, L5, AND H ARE MEASURED AT DATUM PLANE C.

	MILLIMETERS		
DIM	MIN	MAX	
Α	1.40	1.60	
b	0.32	0.52	
b1	0.37	0.57	
С	0.30	0.50	
D	4.40	4.60	
D2	1.40	1.80	
Е	2.40	2.60	
е	1.40	1.60	
Н	4.25	4.45	
L	1.10	1.50	
L2	0.80	1.20	
L3	0.95	1.35	
L4	0.65	1.05	
L5	0.20	0.60	

GENERIC MARKING DIAGRAM*

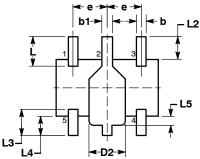


XXXX = Specific Device Code MM = Lot Number = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present.

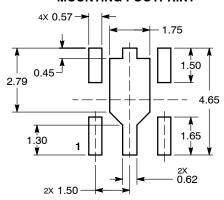
E **TOP VIEW**





BOTTOM VIEW

RECOMMENDED MOUNTING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

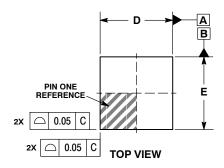
DOCUMENT NUMBER:	98AON47037E	Electronic versions are uncontrolled except when accessed directly from the Document Reposit Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SOT-89, 5 LEAD		PAGE 1 OF 1

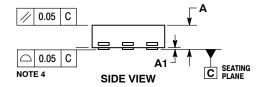
ON Semiconductor and (III) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

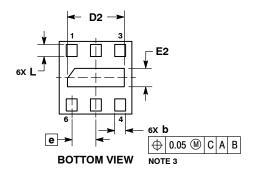


XDFN6 1.20x1.20, 0.40P CASE 711AH **ISSUE O**

DATE 14 SEP 2011







- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION b APPLIES TO PLATED
 TERMINAL AND IS MEASURED BETWEEN
- 0.15 AND 0.25mm FROM TERMINAL TIPS.
 COPLANARITY APPLIES TO ALL OF THE TERMINALS.

	MILLIMETERS			
DIM	MIN	MAX		
Α		0.40		
A1	0.00	0.05		
b	0.13	0.23		
D	1.20 BSC			
D2	0.89 0.99			
E	1.20 BSC			
E2	0.25 0.35			
е	0.40 BSC			
L	0.15	0.25		
L1	0.05	BSC		

GENERIC MARKING DIAGRAM*

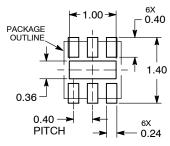


XX = Specific Device Code

MM = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

RECOMMENDED MOUNTING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	98AON59261E Electronic versions are uncontrolled except when accessed directly from the Printed versions are uncontrolled except when stamped "CONTROLLED C		
DESCRIPTION:	XDFN6, 1.20 X 1.20, 0.40P		PAGE 1 OF 1

ON Semiconductor and (III) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer pu

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for LDO Voltage Regulators category:

Click to view products by ON Semiconductor manufacturer:

Other Similar products are found below:

AP7363-SP-13 L79M05TL-E PT7M8202B12TA5EX TCR3DF185,LM(CT TCR3DF24,LM(CT TCR3DF285,LM(CT TCR3DF31,LM(CT TCR3DF31,LM(CT TCR3DF45,LM(CT MP2013GQ-33-Z 059985X NCP4687DH15T1G 701326R TCR2EN28,LF(S NCV8170AXV250T2G TCR3DF27,LM(CT TCR3DF19,LM(CT TCR3DF125,LM(CT TCR2EN18,LF(S AP2112R5A-3.3TRG1 AP7315-25W5-7 IFX30081LDVGRNXUMA1 NCV47411PAAJR2G AP2113KTR-G1 AP2111H-1.2TRG1 ZLDO1117QK50TC AZ1117IH-1.8TRG1 AZ1117ID-ADJTRG1 TCR3DG12,LF MIC5514-3.3YMT-T5 MIC5512-1.2YMT-T5 MIC5317-2.8YM5-T5 SCD7912BTG NCP154MX180270TAG SCD33269T-5.0G NCV8170BMX330TCG NCV8170AMX120TCG NCP706ABMX300TAG NCP153MX330180TCG NCP114BMX075TCG MC33269T-3.5G CAT6243-ADJCMT5T TCR3DG33,LF AP2127N-1.0TRG1 TCR4DG35,LF LT1117CST-3.3 LT1117CST-5 TAR5S15U(TE85L,F) TAR5S18U(TE85L,F) TCR3UG19A,LF TCR4DG105,LF